

RN1968FE(TE85L,F)

RN1968FE(TE85L,F) Information

Numerisener.com	RN1968FE(TE85L,F) Toshiba Semiconductor and Storage Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased TRANS 2NPN PREBIAS 0.1W ES6 SOT-563, SOT-666 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdent@heisener.com	Request a Quote

E-mail: salesdept@heisener.com

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



RN1968FE(TE85L,F) Specifications

	Report errors?
Supplier Device Package	ES6
Package / Case	SOT-563, SOT-666
Mounting Type	Surface Mount
Power - Max	100mW
Frequency - Transition	250MHz
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	300mV @ 250µA, 5mA
DC Current Gain (hFE) (Min) @ Ic, Vce	80 @ 10mA, 5V
Resistor - Emitter Base (R2) (Ohms)	47k
Resistor - Base (R1) (Ohms)	22k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	2 NPN - Pre-Biased (Dual)
Series	-
Package	SOT-563, SOT-666
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Toshiba Semiconductor and Storage
Manufacturer Part Number	RN1968FE(TE85L,F)

RN1968FE(TE85L,F) Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

RN1968FE(TE85L,F) Payment Methods



If you have any question about RN1968FE(TE85L,F), please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com